NSN 5962-01-249-9746

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View Online at https://aerobasegroup.com/nsn/5962-01-249-9746

view Offilite at https://defobasegroup.com/hsh/0302-01-243-3/40
Body Length:
0.640 inches
Body Width:
Between 0.360 inches and 0.420 inches
Body Height:
Between 0.045 inches and 0.090 inches
Maximum Power Dissipation Rating:
1.02 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Wsd: aircraft, galaxy c-5
Features Provided:
Schottky and bipolar and programmable and monolithic
Inclosure Material:
Ceramic or metal
Inclosure Configuration:
Flat pack
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
14 input
Criticality Code Justification:
Feat
Case Outline Source And Designator:
F-6 mil-m-38510
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-0.5 volts power source and 7.0 volts power source
Time Rating Per Chacteristic:
100.00 nanoseconds propagation delay time, low to high level output and 100.00 nanoseconds propagation delay time, high to low level
output
Memory Device Type:
Rom
Special Features:
Weapon system essential
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

24 flat leads

Terminal Type And Quantity:

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N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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